



2204

PATENT APPLICATION  
Attorney's Do. No. 9898-204

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of: Jae-Yoon SIM and Jei-Hwan YOO

Serial No. 09/901,930 Examiner: Not yet assigned

Filed: July 9, 2001 Group Art Unit: 2204

For: NEGATIVE VOLTAGE GENERATOR FOR A SEMICONDUCTOR  
MEMORY DEVICETRANSMITTAL LETTER

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BOX NON FEE AMENDMENT  
Assistant Commissioner for Patents  
Washington, D.C. 20231

SEP 25 2001

TO 3600 MAIL ROOM

Enclosed for filing in the above-referenced application are the following:

Preliminary Amendment  
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Respectfully submitted,

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3/Pre-Amend  
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9-29-01  
PATENT APPLICATION  
Do. No. 9898-204

C.W.HS

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MEMORY DEVICE

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PRELIMINARY AMENDMENT

Please amend the application as follows.

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IN THE SPECIFICATION

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Please replace the paragraph beginning on page 1 at line 3 with the following:

*A1*  
This application claims priority from Provisional Application No. 60/288,746, entitled  
NEGATIVE VOLTAGE GENERATOR IN SEMICONDUCTOR MEMORY DEVICE, filed  
on May 4, 2001, by the same inventors of the present application, the contents of which are  
herein incorporated by reference.

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